

Cat No.: Revision:

#### 7-1S-1000-052 2

# AllnGaP LED DICE

# Part NO.: AOC-112OxC Series

#### Features

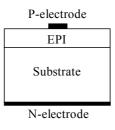
- Orange Color Emission
- Excellent performance and high efficiency
- Great reliability even in harsh environment

### Description

AOC-112OxC series is a orange color emitting AlInGaP LED grown by MOCVD technique. Its structure enables enhanced quantum efficiency and therefore a greater light intensity. This device is designed to suit the growing demand in the compact size electronic goods.

### **Chip Dimensions**





Chip Size : 10.8mil×10.8mil±0.5mil Bonding Pad :  $\phi$ 3.8mil±0.3mil Chip Thickness : 6.5mil±1.0mil

# **Specification and Optical Characteristics**

Measuring Item	Symbol	Condition	Min	Тур	Max	Unit
Forward Voltage	$\mathbf{V}_{\mathrm{F}}$	I <sub>F</sub> =20mA	1.70	-	2.20	V
Reverse Current	Ir	$V_R=-5V$	-	-	1.0	$\mu A$
Dominant Wavelength	λd	I <sub>F</sub> =20mA	600	-	620	nm
Max. Junction Temperature	T <sub>max</sub>	-	$\leq$ 115			°C
Max. DC forward current	$I_{f}$	$Ta = 25^{\circ}C$	$\leq$ 50			mA
Max. pulse forward current (Pulse width 0.1 msec, frequency=1 kHz.)	$\mathrm{I}_{\mathrm{fm}}$	$Ta = 25^{\circ}C$	$\leq$ 100			mA
Storage temperature	T <sub>stg</sub>	Chip on tape	0~40			്റ
		Only chip				

# Available Dominate Wavelength and Iv Matrix

Part No.	Wavelength	≥ 130	≥ 140	≥ 150	≥160	≥ 170	≥ 180	≥ 190	≥ 200	≥ 210	≥ 220	≥230
	Range	mcd	mcd	mcd	mcd	mcd	mcd	mcd	mcd	mcd	mcd	mcd
112OSC	600~610 nm	-	-	-	-	-	-	-	-	-	-	-
112OLC	610~620 nm	-	М	Ν	0	Р	Q	-	-	-	-	-

Not:

1. All measurements are done with AOC's standard testing equipment.

2. Luminance intensity is measured on bare chip.

3. Above contents are subject to change without notice.

Special requests are also welcome, please contact AOC's sale representative for any request.